AMMP-6220 6-20 GHz Low Noise Amplifier

Data Sheet





Description

Avago's AMMP-6220 is a high gain, low-noise amplifier that operates from 6 GHz to 20 GHz. The LNA is designed to be a easy-to-use component for any surface mount PCB application. The broad and unconditionally stable performance makes this LNA ideal for primary, sub-sequential or driver low noise gain stages. Intended applications include microwave radios, 802.16, automotive radar, VSAT, and satellite receivers. Since one part can cover several bands, the AMMP-6220 can reduce part inventory and increase volume purchase options. The LNA has integrated 50 Ω I/O match, DC blocking, self-bias and choke to eliminate complex tuning and assembly processes typically required by hybrid (discrete-FET) amplifiers. The package is full SMT compatible with backside grounding and I/O to simplify assembly.

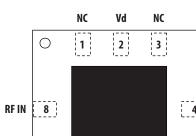
Features

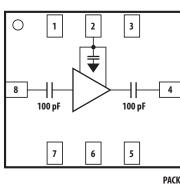
- 5x5 mm surface mount package
- Broad Band performance 6-20 GHz
- Low 2.5 dB typical noise figure
- High 22 dB typical gain
- 50 Ω input and output match
- Single 3 V (55 mA) supply bias
- 100% RF test in package

Applications

- Microwave radio systems
- Satellite VSAT
- WLL and MMDS loops

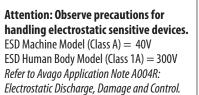
Functional Block Diagram





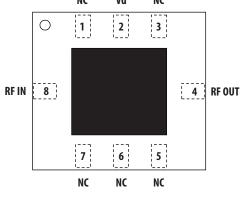
PIN	FUNCTION
1	
2	Vd
3	
4	RFout
5	
6	
7	
8	RFin

PACKAGE BASE GND



Note: MSL Rating = Level 2A

Package Diagram







Please refer to hazardous substances table on page 7.

Electrical Specifications

- 1. Small/Large -signal data measured in a fully de-embedded test fixture form $T_A = 25^{\circ}C$.
- 2. Pre-assembly into package performance verified 100% on-wafer per AMMC-6220 published specifications.
- 3. This final package part performance is verified by a functional test correlated to actual performance at one or more frequencies.
- 4. Specifications are derived from measurements in a 50 W test environment. Aspects of the amplifier performance may be improved over a more narrow bandwidth by application of additional conjugate, linearity, or low noise (Γopt) matching.

Table 1. RF Electrical Characteristics

Parameter	Min	Тур.	Мах	Sigma	Unit
Small-signal Gain, Ga		22		0.5	dB
Noise Figure into 50 Ω, NF		2.5		0.2	dB
Output Power at 1dB Gain Compression, P-1dB		+10		0.8	dBm
Third Order Intercept Point; Δf=100MHz; Pin=-20dBm, OIP3		+20		1.1	dBm
Input Return Loss, RLin		-12		0.3	dB
Output Return Loss, Rlout		-16		0.7	dB
Reverse Isolation, Isol		-45		0.5	dB

Table 2. Recommended Operating Range

- 1. Ambient operational temperature $TA = 25^{\circ}C$ unless otherwise noted.
- 2. Channel-to-backside Thermal Resistance (Tchannel (Tc) = 34°C) as measured using infrared microscopy. Thermal Resistance at backside temperature (Tb) = 25°C calculated from measured data.

	Specific	Specifications			
Description	Min.	Typical	Max.	Unit	Comments
Drain Supply Current, Id		55	70	mA	(Vd = 3 V, Under any RF power drive and temperature)

Table 3. Thermal Properties

arameter Test Conditions		Value	
Thermal Resistance, θch-b		θ ch-b = 27 °C/W	

Absolute Minimum and Maximum Ratings

Table 4. Minimum and Maximum Ratings

		Specific	Specifications			
Description	Pin	Min.	Max.	Unit	Comments	
Drain Supply Voltage	Vd		7	V		
Drain Current	Id		100	mA		
RF Input Power (Pin)	RFIN		15	dBm	CW	
Channel Temperature			+150	°C		
Storage Temperature		-65	+150	°C		
Maximum Assembly Temperature			+300	°C	60 second maximum	

Notes:

1. Operation in excess of any one of these conditions may result in permanent damage to this device.

Selected performance plots

These measurements are in 50Ω test environment at $T_A = 25$ °C, Vd = 3V, Id = 55 mA. Aspects of the amplifier performance may be improved over a narrower bandwidth by application of additional conjugate, linearity or low noise (Fopt) matching.

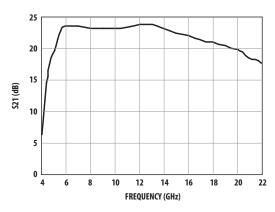


Figure 1. Gain.

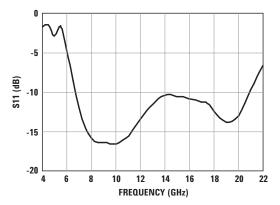


Figure 3. Input return loss.

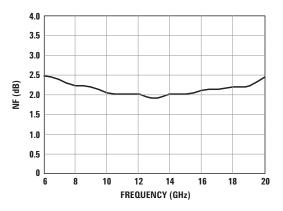


Figure 5. Noise figure.

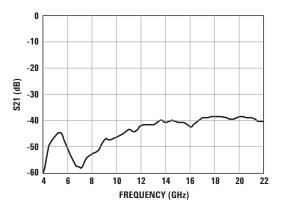


Figure 2. Isolation.

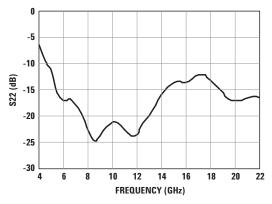


Figure 4. Output return loss.

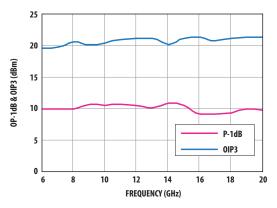


Figure 6. Typical power, OP-1dB and OIP3.

Over Temperature Performance Plots

These measurements are in 50Ω test environment at $T_A = 25$ °C, Vd = 3V, Id = 55 mA. Aspects of the amplifier performance may be improved over a narrower bandwidth by application of additional conjugate, linearity or low noise (Fopt) matching.

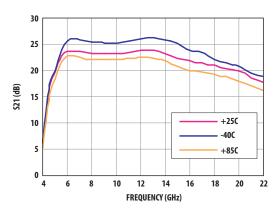


Figure 7. Gain over temperature.

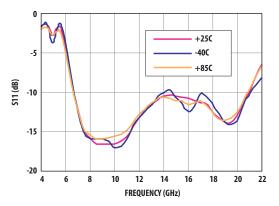


Figure 9. Input return loss over temperature.

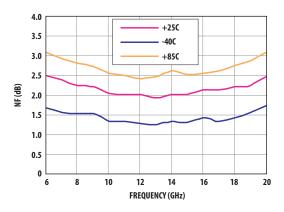


Figure 11. NF over temperature.

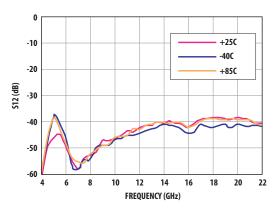


Figure 8. Isolation over temperature.

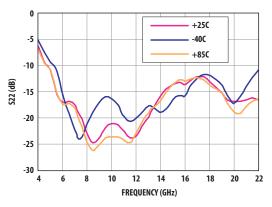


Figure 10. Output return loss over temperature.

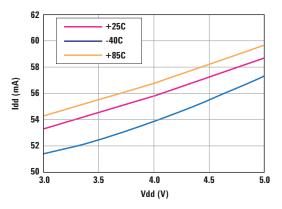


Figure 12. Bias current over temperature.

Over Voltage plots

These measurements are in 50Ω test environment at $T_A = 25$ °C, Vd = 3V, Id = 55 mA. Aspects of the amplifier performance may be improved over a narrower bandwidth by application of additional conjugate, linearity or low noise (Fopt) matching.

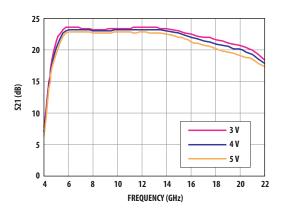


Figure 13. Gain over Vdd.

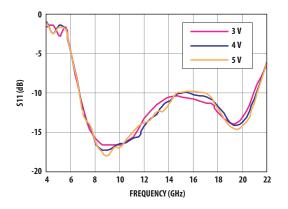


Figure 15. Input RL over Vdd.

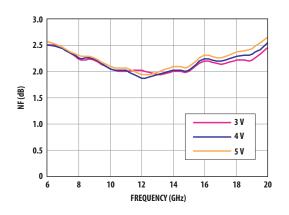


Figure 17. Noise figure over Vdd.

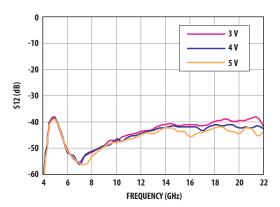


Figure 14. Isolation over Vdd.

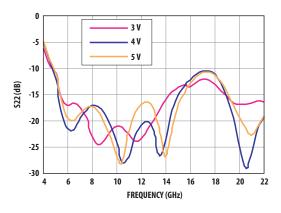


Figure 16. Output return loss over temperature.

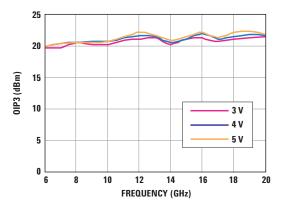


Figure 18. OIP3 over Vdd.

Biasing and Operation

The AMMC-6220 is normally biased with a single positive drain supply connected to both V_D pin through bypass capacitors as shown in Figure 19. The recommended supply voltage is 3 V. It is important to have 0.1 μ F bypass capacitor, and the capacitor should be placed as close to the component as possible.

The AMMC-6220 does not require a negative gate voltage to bias any of the three stages. No ground wires are needed because all ground connections are made with plated through-holes to the backside of the package.

Refer the Absolute Maximum Ratings table for allowed DC and thermal conditions.

Application Circuit

Figure 19. Typical application

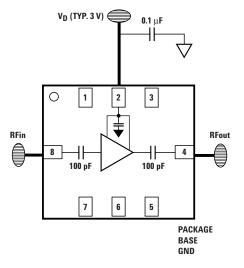




Figure 21. Demonstration board (available upon request)

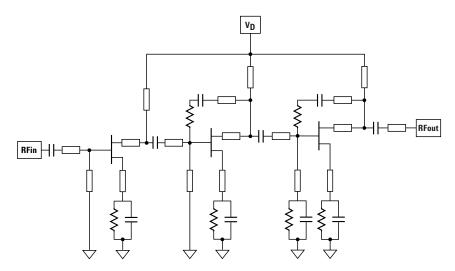


Figure 20. Simplified MMIC schematic

Typical Scattering Parameters

Please refer to <http://www.avagotech.com> for typical scattering parameters data.

Package Dimension, PCB Layout and Tape and Reel information

Please refer to Avago Technologies Application Note 5520, AMxP-xxxx production Assembly Process (Land Pattern A).

AMMP-6220 Part Number Ordering Information

Part Number	Container		
AMMP-6220-BLK	10	Antistatic bag	
AMMP-6220-TR1	100	7" Reel	
AMMP-6220-TR2	500	7" Reel	



Names and Contents of the Toxic and Hazardous Substances or Elements in the Products 产品中有毒有害物质或元素的名称及含量

Part Name		Toxic and Hazardous Substances or Elements 有毒有害物质或元素							
	Lead (Pb) 铅	Mercury (Hg) 汞	Cadmium (Cd) 镉	□ Hexavalent (Cr(VI)) 六价	、 Polybrominated biphenyl (PBB) 多	Polybrominated diphenylether (PBDE)			
部件名称	(Pb)	(Hg)	(Cd)	铬(Cr(VI))	溴联苯(PBB)	多溴二苯醚(PBDE)			
100pF capacitor	×	0	0	0	0	0			
exceeds the concent (The enterprise may the actual situations.	further explain th				ne table in accordance with	1			
×:表示该有毒有	「害物质至少在	该部件的某	一均质材料中	均在 SJ/T 11363-20 的含量超出 SJ/T 1 因进行进一步说明	1363-2006 标准规定	:要求以下。 的限量要求。			

Note: EU RoHS compliant under exemption clause of "lead in electronic ceramic parts (e.g. piezoelectronic devices)"

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